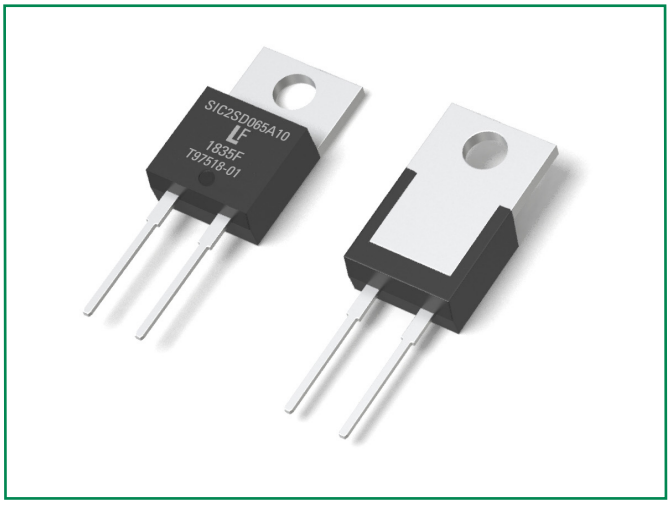
GEN2 SiC Schottky Diode
LSIC2SD065A10A, 650 V, 10 A, TO-220-2L

LSIC2SD065A10A 650 V, 10 A SiC Schottky Barrier Diode

HF RoHS Pb



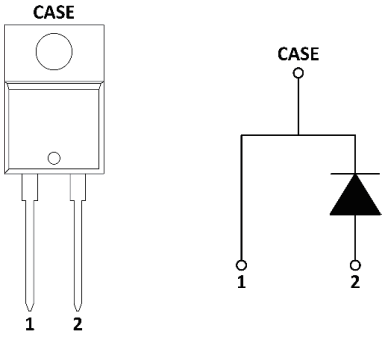
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- AEC-Q101 qualified
- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS
  RoHS conform
- Littelfuse "HF" logo = **HF**
  Halogen Free
- Littelfuse "Pb-free" logo = Pb
  Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	650	V
DC Blocking Voltage	V_R	T_J = 25 °C	650	V
Continuous Forward Current	I_F	T_C = 25 °C	27	A
		T_C = 135 °C	12.5	
		T_C = 147 °C	10	
Non-Repetitive Forward Surge Current	I_{FSM}	T_C = 25 °C, T_P = 10 ms, Half sine pulse	48	A
Power Dissipation	P_{Tot}	T_C = 25 °C	100	W
		T_C = 110 °C	43	
Operating Junction Temperature	T_J	-	-55 to 175	°C
Storage Temperature	T_{STG}	-	-55 to 150	°C
Soldering Temperature	T_{SOLD}	-	260	°C

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Electrical Characteristics (T_J =25 °C unless otherwise specified)

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V_F	I_F = 10 A, T_J = 25 °C	-	1.5	1.8	V
		I_F = 10 A, T_J = 175 °C	-	1.85	-	
Reverse Current	I_R	V_R = 650 V, T_J = 25 °C	-	<1	50	µA
		V_R = 650 V, T_J = 175 °C	-	25	-	
Total Capacitance	C	V_R = 1 V, f = 1 MHz	-	470	-	pF
		V_R = 200 V, f = 1 MHz	-	60	-	
		V_R = 400 V, f = 1 MHz	-	43	-	
Total Capacitive Charge	Q_C	V_R = 400 V, $Q_c = \int_0^{V_R} C(V)dV$	-	30	-	nC

Thermal Characteristics

Characteristics	Symbol	Value	Unit
Thermal Resistance	$R_{\theta JC}$	1.5	°C/W

Figure 1: Typical Foward Characteristics

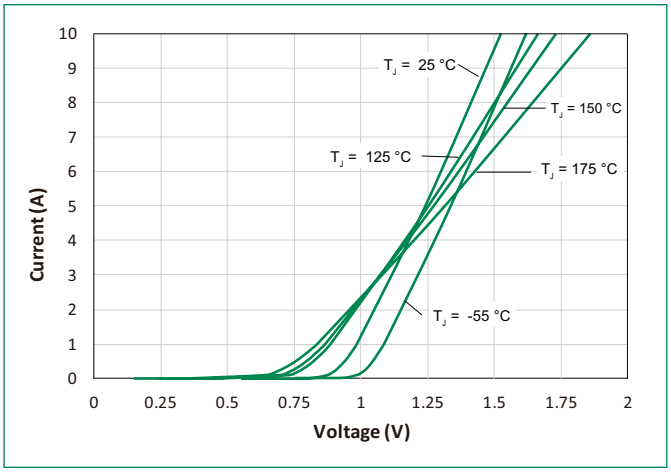

Figure 2: Typical Reverse Characteristics

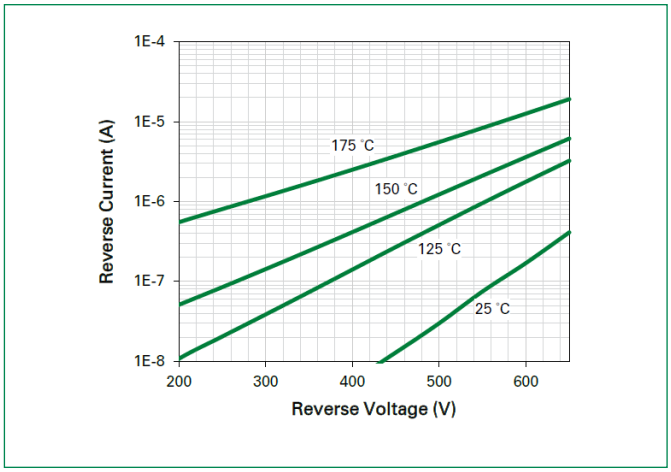

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Figure 3: Power Derating

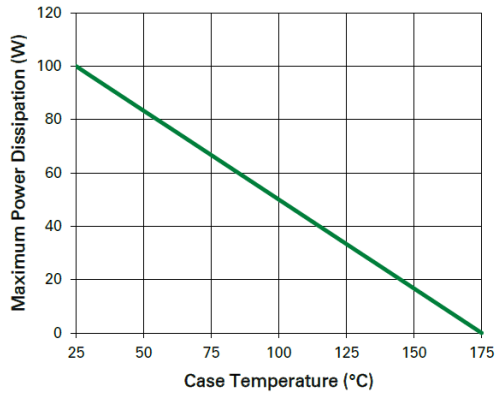


Figure 4: Current Derating

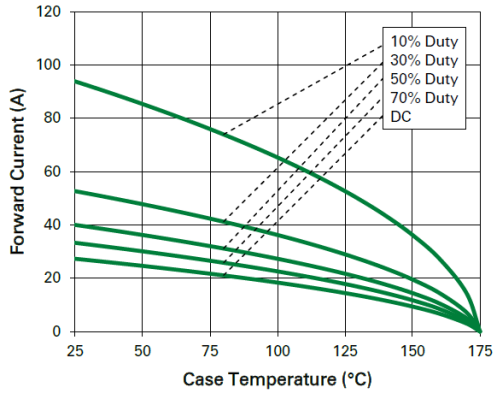


Figure 5: Capacitance vs. Reverse Voltage

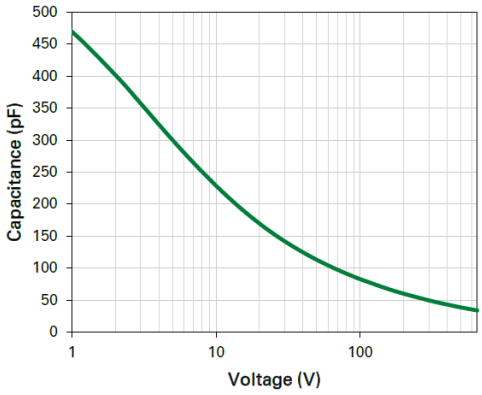


Figure 6: Capacitive Charge vs. Reverse Voltage

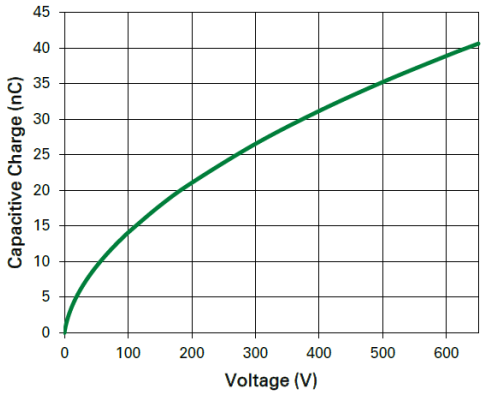


Figure 7: Stored Energy vs. Reverse Voltage

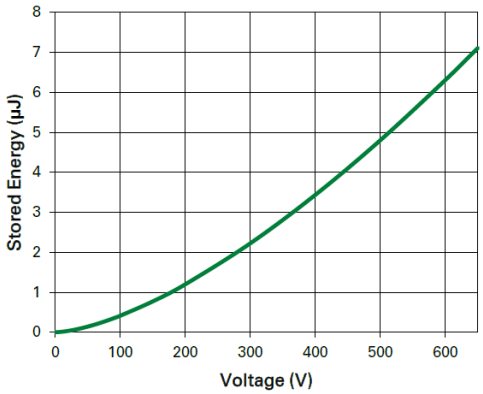
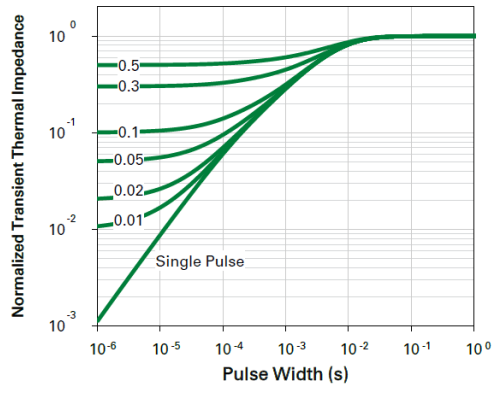


Figure 8: Transient Thermal Impedance



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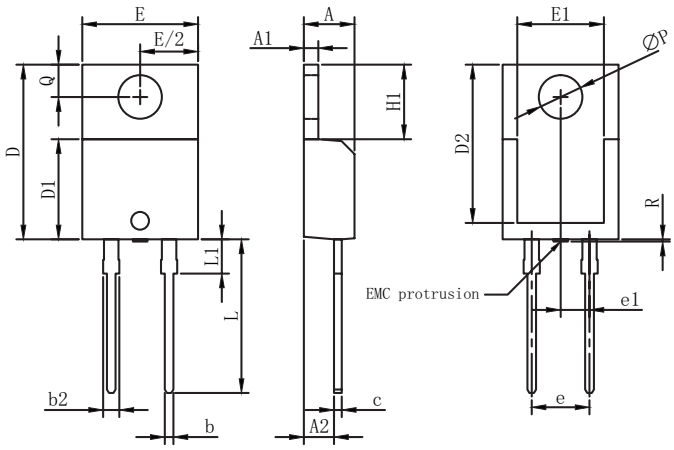
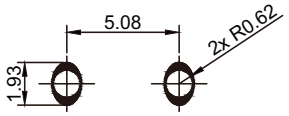
Dimensions-Package TO-220-2L



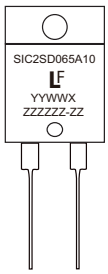
Recommended Solder Pad Layout



UNIT: mm

Symbol	Millimeters		
	Min	Nom	Max
A	4.32	4.45	4.70
A1	1.14	1.27	1.40
A2	2.20	-	2.74
b	0.69	-	0.90
b2	1.17	-	1.62
c	0.36	-	0.60
D	14.90	-	15.90
D1	8.62	-	9.40
D2	12.50	-	12.95
E	9.70	10.18	10.36
E1	7.57	7.61	8.30
e1	-	2.54	-
e	5.03	5.08	5.13
H1	6.30	6.55	6.80
L	12.88	13.50	14.00
L1	2.39	-	3.25
øP	3.50	3.84	3.96
Q	2.65	-	3.05
R	-	-	0.25

Part Numbering and Marking System



SIC	= SiC Diode
2	= Gen2
SD	= Schottky Diode
065	= Voltage Rating (650 V)
A	= TO-220 Package (2 Lead)
10	= Current Rating (10 A)
YY	= Year
WW	= Week
X	= Special Code
ZZZZZZ-ZZ	= Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD065A10A	SIC2SD065A10	Tube(50pcs)	1000

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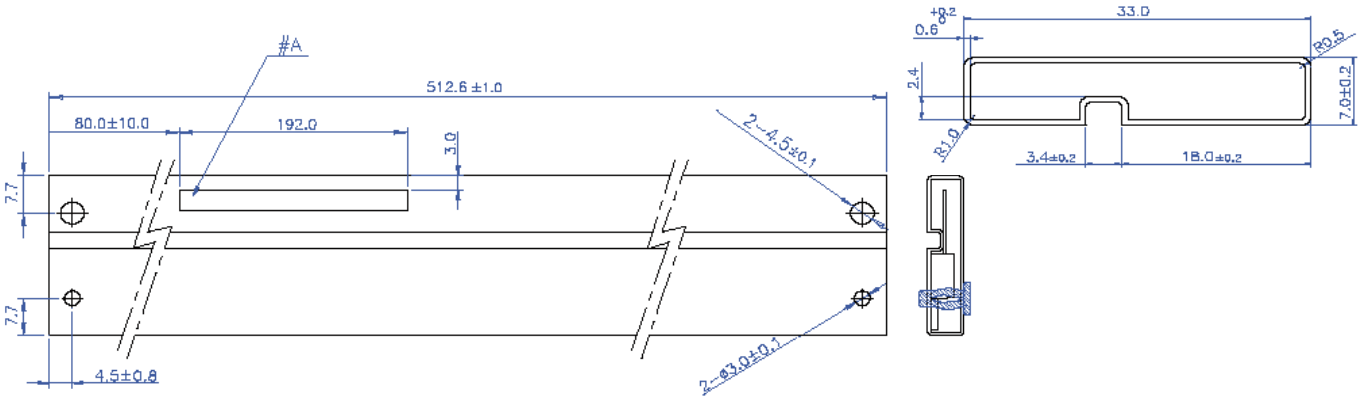
Packing Specification (Tube for TO-220-2L)



[NOTE]

1. TUBE
   - MATERIAL : PVC / PET (WITH ANTISTATIC COATING)
   - COLOR : TRANSPARENCY, RED, YELLO
   - MARKING #A : BLACK COLOR, LETTER STYLE : Arial
   - Tube Surface Resistance : 10^{5}~10^{11} Ω/square
   - ESD (Electro Static Discharge) : less than 100 [volts], 6 Months
   - CAMBAR : 1.5 MAX
2. PIN
   - COLOR : GREEN (ONE PIN MUST BE INSERTED IN LEFT-SIDE OF "□ANTISTATIC~" AND ANOTHER PIN IS FREE.)

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